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INFORMATION DISCLOSURE STATEMENT TRANSMITTAL

To Commissioner For Patents

Enclosed herewith is a Form PTO-1449, any required copies of documents listed thereon, and any concise explanation of their relevance is indicated below per 37 CFR 1.97.

<i>Application Number</i>	
<i>Filing Date</i>	
<i>First Named Inventor</i>	ROCHEFORT, CHRISTELLE
<i>Group Art Unit</i>	
<i>Examiner Name</i>	
<i>Atty. Docket Number</i>	GB040080US

U.S. PATENT DOCUMENTS

Examiner Initials*	Cite No. ¹	Document Number (ctry ² -no. ³ -kind ⁴ , if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns Lines, Where Relevant Passages or Relevant Figures Appear
/MW/	1	US- 2003/0136994	07/24/2003	MARTIN POPP ET AL.	
/MW/	2	US- 6 337 499	01/08/2002	WOLFGANG WERNER	
/MW/	3	US- 6 512 267	01/28/2003	KINZER DANIEL ET AL.	
		US-			
		US-			
		US-			

FOREIGN PATENT DOCUMENTS

Examiner Initials*	Cite No. ¹	Document Number (ctry ² -no. ³ -kind ⁴ , if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of cited document	Pages, Columns Lines, Where Relevant Passages or Relevant Figures Appear	T ⁵

NON-PATENT LITERATURE DOCUMENTS

Examiner Initials*	Cite No. ¹	Include name of the author (in capital letters), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ⁵
/MW/	1	ROCHEFORT C. ET AL: "MANUFACTURING OF HIGH ASPECT-RATIO P-N JUNCTIONS USING VAPOR PHASE DOPING FOR APPLICATION IN MULTI-RESURF DEVICES"; PROCEEDINGS OF THE 14 TH INTERNATIONAL SYMPOSIUM ON POWER SEMICONDUCTOR DEVICES AND ICs; 2002 pp 237-240.	

Examiner Signature	/Mary Wilczewski/	Date Considered	03/03/2008
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*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

¹Unique citation designation number. ²See attached Kinds of U.S. Patent Documents. ³Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the